

Applicant : Vishnu K. Agarwal

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Serial No. : 09/910,661

: 1763

Filed

: July 20, 2001

Examiner

Group Art Unit

: George Goudreau

Title

: METHOD AND APPARATUS FOR ENDPOINTING A CHEMICAL-MECHANICAL PLANARIZATION PROCESS

Box Non-Fee Amendment Commissioner of Patents Washington, D.C. 20231

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TC 1700

DECLARATION UNDER 37 C.F.R. § 1, 131

Sir:

I, Vishnu K. Agarwal, declare the following:

- I am a named inventor on the above referenced patent application. 1.
- I have been employed as an engineer for Micron Technology since 2. June 18, 1997.
- Prior to September 4, 1997, I conceived of the apparatus for detecting the endpoint of a planarizing process of a microelectronic substrate which is claimed in the afore-mentioned patent application. More particularly, I conceived of directing slurry coming out of a planarization pad to a vaporizer using a pump along with an optional filter or diluter. The vaporized slurry is then analyzed for the species of interest in a mass spectrometer, and a change in slurry concentration as determined by the mass spectrometer is used for controlling the planarization process. Transport of the slurry from a drain line from the planarizing platen, vaporization, analysis and communication of the mass spectrometer results to the controller of the planarization process can take less than two seconds.
 - Prior to September 4, 1997, and within four days of conceiving of using a mass spectrometer to detect a change in slurry concentration and control a planarization process, I prepared Invention Disclosure Statement No. 97-800 which set forth the foregoing inventive idea. The invention disclosure statement was submitted to my employer, Micron Technology, Inc., for the purpose of preparing a patent application. The invention disclosure statement was thereafter submitted to patent counsel for preparation of the present application. A copy of the invention disclosure statement submitted to my employer and to patent counsel is attached hereto as Exhibit A.

The aforementioned statements based on my own knowledge are true and/or are based on information believed by me to be true. I acknowledge that willful false statements and the like are punishable by fine or imprisonment, or both, and may jeopardize the validity of the subject patent application or any patent issuing thereon.

Vishnu K. Agarwal

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INVENTOR(S): _Vishnu K.	Agarwal
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DESCRIPTION

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Title of invention:

A method for the on-line end point detection of CMP.

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2.2 Brief description:

In this invention a method for the end point detection of CMP process is disclosed. A continuous sample of slurry, coming out of the pad, is directed to vaporizer using a pump/ pump and filter combination/ pump and dilution . The vaporized slurry is analyzed for the species of the interest in mass spectrometer. The change in slurry concentration as determined by the mass spectrometer is used for the controlling the process.

Also attach a complete description, including drawings or sketches and articles relevant to the invention. Legible photocopies of laboratory notebooks are acceptable.

Figure 1 shows the block diagram of the detection system after integration with the CMP tool. This ligure also indicates the time taken in each step. The transport of the slurry from the drain line, vaporization, concentration analysis are performed and subsequently communicated with the controller on CMP tool in less than 2 second. This is continuous concentration monitoring hence no stabilization time is associated in region of interest as indicated in rigure 2.

The concentration of W, Al, Cu and Si in slurry with various combination of removal rate and slurry flow rate is given in table 1. The data in this table show that the concentration level under various possible conditions is well within the capability of

INFORMATION CONCERNING CONCEPTION OF INVENTION

CONCEPTION AND DOCUMENTATION OF THE INVENTION 3.1

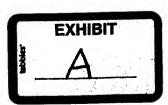
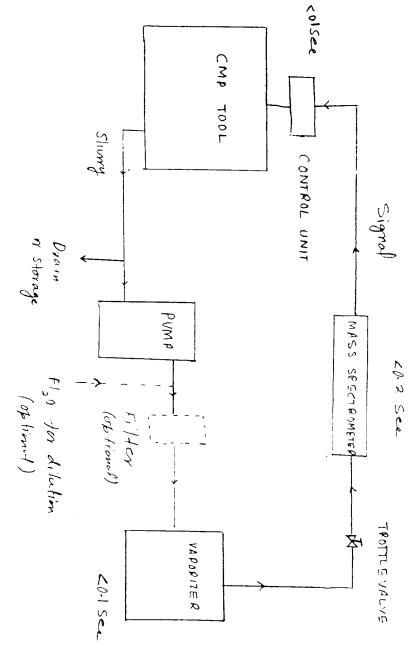


FIGURE -1: BLOCK DIAGRAM OF END POINT DETECTION SYSTEM USING VAPORIZER AND MASS SPECTROMETER



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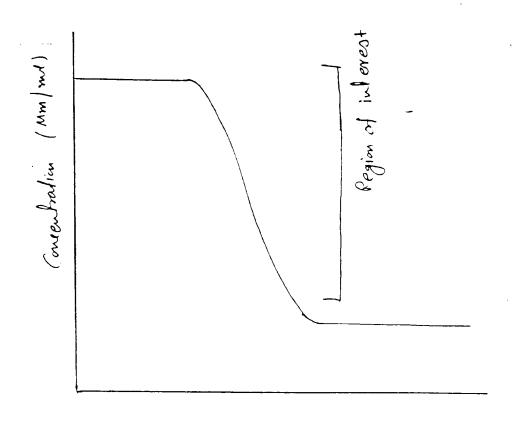


Table-1: Concentration of various species under different processing conditions

Concentr (ug/m1),	1477.	29.5	206.7	4.13	682.9	13.6	153.1	3.06	14776	295.5	2067.	41.3	6829.	136.5	1531.	30.6
Material being removed	*	*	Al	Al	Cu	Cu	SĴ	Si,	≽	≽	Al	AL	Cn	Cu	Si	Si
Slurry flow rate (ml/min)	10	200	10	200	10	200	01	200	10	200	01	500	10	500	01	200
Pemoval Rate (A/sec)	10	10	10	10	10	10	10	10	100	100	100	100	100	100	100	100

aption: Wafer Size is 8"

- a. Identify the dee when you first conceive the invention. (If not sure, give the earliest date of which you are sure.)
- b. To whom was the idea first described and on what date? (Other than a co-inventor.)Dr. Gurtej Sandhu,
- c. Identify the date of the first tangible record such as computer simulation, tape out, drawing or written description. Please specify type and location.

2 CONCEPTION OF THE INVENTION

a. Please identify related invention disclosures, patents or other publications describing similar ideas, and other companies working in the same field. Attach copies, if available.

No patent or publication mentioning this method for the CMP end point detection is not in my knowledge.

- b. What is the closest technology, of which you are aware? Chemical analysis method other than this method.
- c. Identify the advantages of this invention over previous technology.

On line and real time analysis, The point of interest can find out and communicated in less than 2 sec.

Little time for development. The pump and vaporizer are available commercially used f or DLI in CVD. The mass spetrometer is also available commercially from various manufacturer.

Compatiable with the clean room.

Can be used for any type of CMP and for various recipes. Highly sensitive.

3.3 IMPORTANT DATES

- b. Have any articles describing your invention been published? No If yes, list author(s), title of article, publication and date.
- c. Have any engineering samples been given out? No_____ If yes, to whom and on what date?
- d. Has any product using the invention been sold or offered for sale? No If yes, to whom and on what date?

3.4 DISPOSITION OF THE INVENTION

a. When will (or did) Micron begin use of the invention

b. When will (or did) Micron begin production of this invention?

3.5 MISCELLANEOUS INFORMATION

- a. Was the invention developed during a joint development agreement or other contract with an outside company? _No____
- b. Please list developmental work outside of the company (including Government proposal or contract). Not applicable

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